

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

SFT1407 — General-Purpose Switching Device **Applications**

Features

- · Motor drive application.
- · Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		45	٧
Gate-to-Source Voltage	VGSS		±20	٧
Drain Current (DC)	ID		14	Α
Drain Current (PW≤10μs)	IDP	PW≤10μs, duty cycle≤1%	56	Α
Allowable Power Dissipation	PD		1.0	W
		Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	45			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =45V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =7A	5.8	9.7		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=7A, VGS=10V		21	28	mΩ
	R _{DS} (on)2	I _D =7A, V _{GS} =4V		29	41	mΩ

Marking: T1407 Continued on next page.

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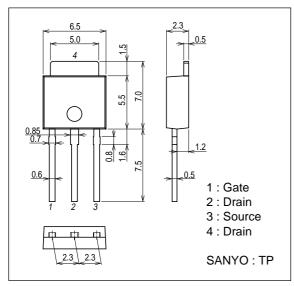
SFT1407

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Parameter	Symbol	Symbol Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	VDS=20V, f=1MHz		2225		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		260		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		190		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		27		ns
Rise Time	t _r	See specified Test Circuit.		50		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		150		ns
Fall Time	tf	See specified Test Circuit.		80		ns
Total Gate Charge	Qg	V _{DS} =24V, V _{GS} =10V, I _D =14A		40		nC
Gate-to-Source Charge	Qgs	V _{DS} =24V, V _{GS} =10V, I _D =14A		6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =24V, V _{GS} =10V, I _D =14A		8		nC
Diode Forward Voltage	V _{SD}	I _S =14A, V _{GS} =0V		0.92	1.2	V

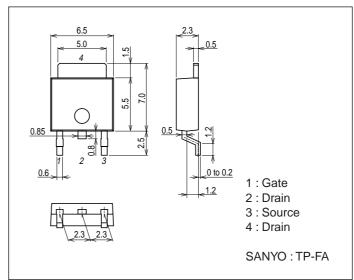
Package Dimensions

unit : mm (typ) 7518-004

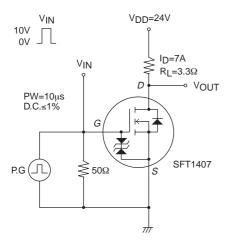


Package Dimensions

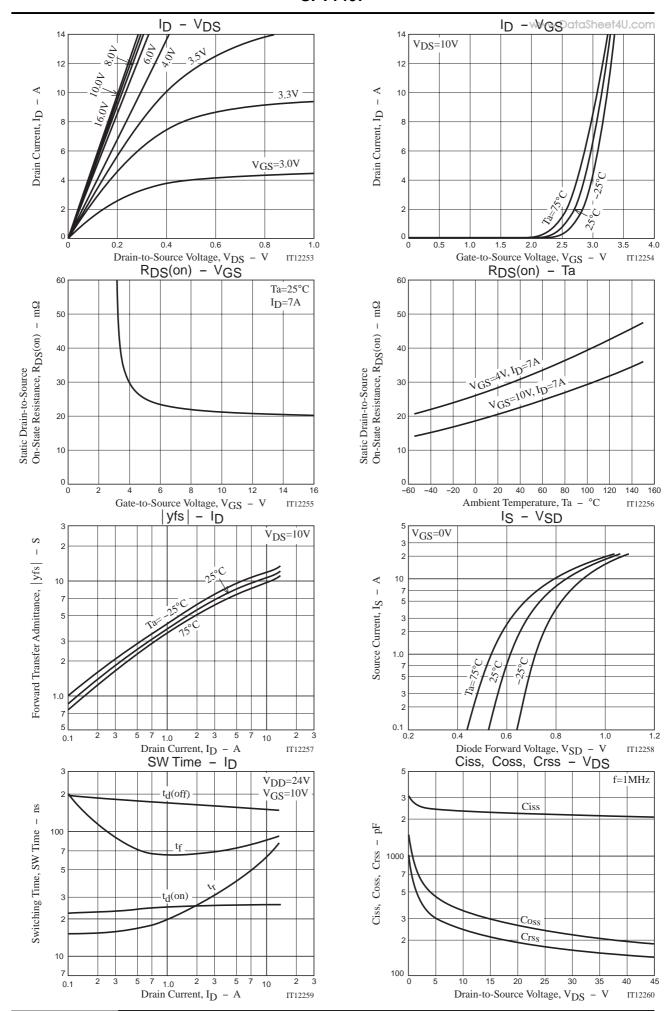
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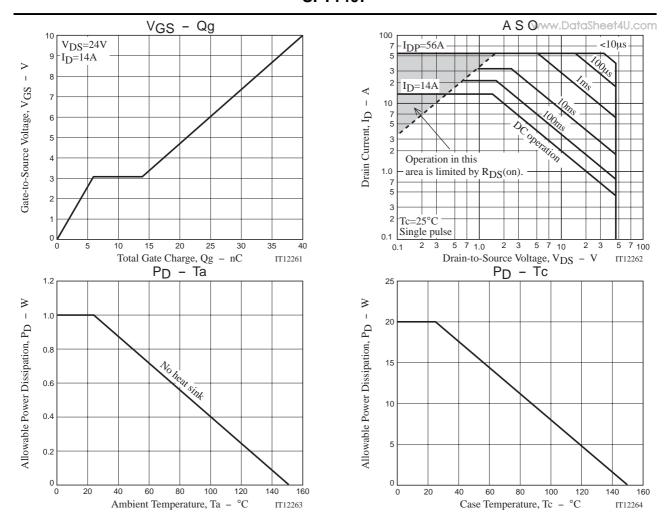


Switching Time Test Circuit



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Note on usage: Since the SFT1407 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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